

isc Silicon PNP Power Transistor

DESCRIPTION

- DC Current Gain-
- : h_{FE}= 40(Min)@ I_C= -0.15A
- · Collector-Emitter Sustaining Voltage -
- : V_{CEO(SUS)}= -45V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



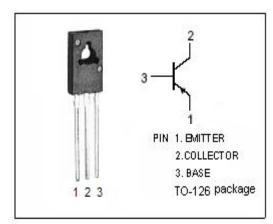
 Designed for use in audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

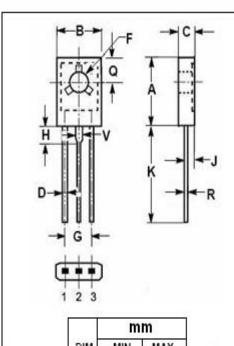
ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-45	V	
V _{CEO}	Collector-Emitter Voltage	-45	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
Ic	Collector Current-Continuous	-1.5	А	
I _B	Base Current-Continuous	-0.5	А	
Pc	Collector Power Dissipation @ T _C =25℃	13	W	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	5.0	°C/W





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DIM	MIN	MAX	
Α	10.70	10.95	
В	7.70	7.90	
C	2.60	2.80	
D	0.66	0.86	
F	3.10	3.30	
G	4.48	4.68	
Н	2.00	2.20	
J	1.35	1.55	
K	15.30	16.30	
Q	3.70	3.90	
R	0.40	0.60	
٧	1.17	1.37	



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BD134

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = -50mA ; I _B =0	-45			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -0.5A; I _B = -0.05A			-0.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -0.5A; V _{CE} = -2V			-1.3	V
Ісво	Collector Cutoff Current	V _{CB} = -45V; I _E = 0			-100	μ А
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C =0			-1.0	mA
h _{FE-1}	DC Current Gain	I _C = -150mA ; V _{CE} = -2V	40		250	
h _{FE-2}	DC Current Gain	Ic= -0.5A; Vc== -2V	25			
f⊤	Current-Gain—Bandwidth Product	I _C =-250mA;V _{CE} =-10V,f _{test} = 1.0MHz	3.0			MHz

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